ON Semiconductor

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Onsemi

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MBR2080CT, MBR2090CT, MBR20100CT

SWITCHMODE™ Power Rectifiers

This series uses the Schottky Barrier principle with a platinum barrier metal. These state-of-the-art devices have the following features:

Features

- 20 A Total (10 A Per Diode Leg)
- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Shipped 50 units per plastic tube
- Pb-Free Packages are Available*

Mechanical Characteristics:

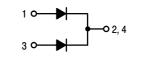
- Case: Epoxy, Molded
- Weight: 1.9 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds



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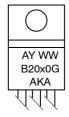
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MARKING DIAGRAM



| А | = Assembly Location | |
|-------|-----------------------|--|
| Y | = Year | |
| WW | = Work Week | |
| B20x0 | = Device Code | |
| х | = 8, 9 or 10 | |
| G | = Pb-Free Device | |
| AKA | = Polarity Designator | |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MAXIMUM RATINGS (Per Diode Leg)

| | | MBR | | | | |
|--|--|------------------------------|------------|---------|------|--|
| Rating | Symbol | 2080CT | 2090CT | 20100CT | Unit | |
| Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage | V _{RRM} V _{RWM} V _R | 80 | 90 | 100 | V | |
| Average Rectified Forward Current (Rated V_R) T_C = 133°C | I _{F(AV)} | 10 | | | A | |
| Peak Repetitive Forward Current (Rated V _R , Square Wave, 20 kHz) T _C = 133°C | I _{FRM} | 20 | | | A | |
| Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz) | IFSM | 150 | | | A | |
| Peak Repetitive Reverse Surge Current (2.0 µs, 1.0 kHz) | I _{RRM} | 0.5 | | А | | |
| Operating Junction Temperature (Note 1) | TJ | - 65 to +175 | | | °C | |
| Storage Temperature | T _{stg} | -65 to +175 | | | °C | |
| Voltage Rate of Change (Rated V _R) | dv/dt | 10,000 | | | V/μs | |
| THERMAL CHARACTERISTICS | | | | | | |
| Maximum Thermal Resistance Junction-to-Case Junction-to-Ambient | $R_{	extsf{	heta}JC}$ $R_{	extsf{	heta}JA}$ | 2.0 60 | | | °C/W | |
| ELECTRICAL CHARACTERISTICS (Per Diode Leg) | | | | | | |
| $\label{eq:maximum lnstantaneous Forward Voltage (Note 2) \\ (i_F = 10 \mbox{ Amps, } T_C = 125^{\circ}C) \\ (i_F = 10 \mbox{ Amps, } T_C = 25^{\circ}C) \\ (i_F = 20 \mbox{ Amps, } T_C = 125^{\circ}C) \\ (i_F = 20 \mbox{ Amps, } T_C = 25^{\circ}C) \\ (i_F = 20$ | VF | 0.75 0.85 0.85 0.95 | | | V | |
| Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^{\circ}C$) (Rated dc Voltage, $T_C = 25^{\circ}C$) | i _R | | 6.0 0.1 | | mA | |

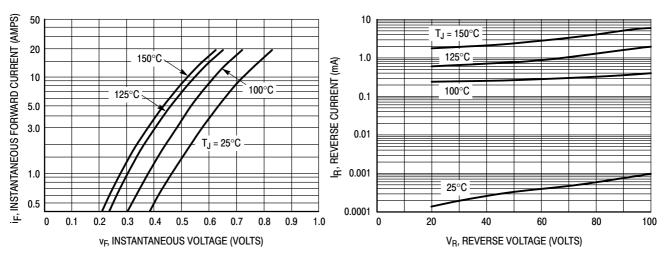
1. The heat generated must be less than the thermal conductivity from Junction–to–Ambient: $dP_D/dT_J < 1/R_{\theta JA}$. 2. Pulse Test: Pulse Width = 300 µs, Duty Cycle \leq 2.0%.

ORDERING INFORMATION

| Device | Package | Shipping [†] | |
|-------------|---------------------|-----------------------|--|
| MBR2080CT | TO-220 | 50 Units / Rail | |
| MBR2080CTG | TO-220 (Pb-Free) | | |
| MBR2090CT | TO-220 | 50 Units / Rail | |
| MBR2090CTG | TO-220 (Pb-Free) | | |
| MBR20100CT | TO-220 | 50 Units / Rail | |
| MBR20100CTG | TO-220 (Pb-Free) | | |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MBR2080CT, MBR2090CT, MBR20100CT



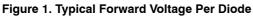


Figure 2. Typical Reverse Current Per Diode

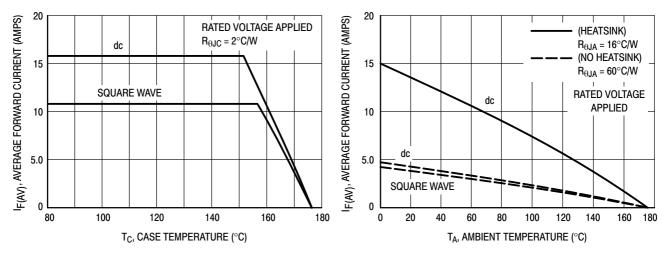


Figure 3. Typical Current Derating, Case, Per Leg

Figure 4. Typical Current Derating, Ambient, Per Leg

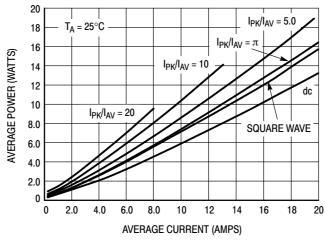
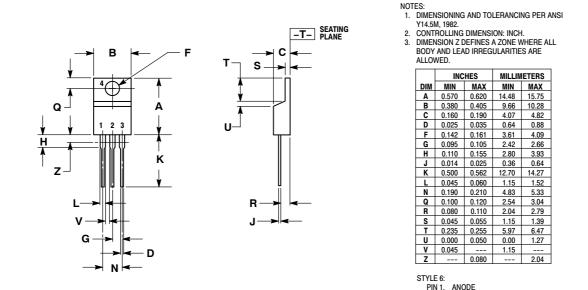


Figure 5. Average Power Dissipation and Average Current

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PACKAGE DIMENSIONS

TO-220 CASE 221A-09 ISSUE AF



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